

MS1329

RF & MICROWAVE TRANSISTORS VHF FM APPLICATIONS

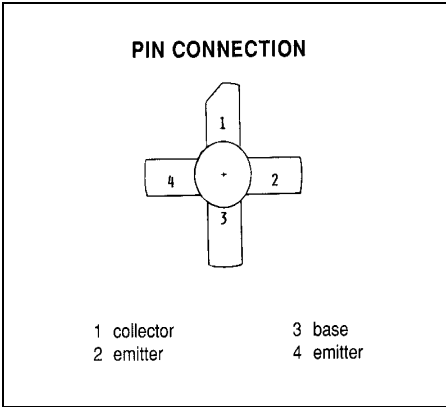
Features

- 150 MHz
- 28 VOLTS
- P_{OUT} = 60W
- G_P = 7.0 dB MINIMUM
- COMMON EMITTER CONFIGURATION



DESCRIPTION:

The MS1629 is an epitaxial silicon NPN transistor designed primarily for 12.5 V Class C, AM amplifier applications in the 118 – 136 MHz and 28 V Class C ground station transmitters. Emitter ballast resistors and gold metalization provide optimum VSWR capability.



ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C)

| Symbol | Parameter | Value | Unit |
|-------------------|---------------------------|-------------|------|
| V _{CBO} | Collector- Base Voltage | 65.0 | V |
| V _{CEO} | Collector-Emitter Voltage | 35.0 | V |
| V _{EBO} | Emitter-Base Voltage | 4.0 | V |
| P _{DISS} | Power Dissipation | 75.0 | W |
| I _C | Collector current | 6.5 | A |
| T _J | Junction Temperature | +200 | °C |
| T _{STG} | Storage Temperature | -65 to +150 | °C |

Thermal Data

| | | | |
|----------------------|----------------------------------|-----|------|
| R _{TH(J-C)} | Thermal Resistance Junction-Case | 2.3 | °C/W |
|----------------------|----------------------------------|-----|------|

ELECTRICAL SPECIFICATIONS (T_{case} = 25°C)
STATIC

| Symbol | Test Conditions | | Value | | | Unit |
|-------------------|-------------------------|-------------------------|-------|------|------|------|
| | | | Min. | Typ. | Max. | |
| BV _{ces} | I _C = 200mA | V _{BE} = 0 mA | 65.0 | --- | --- | V |
| BV _{ceo} | I _C = 200 mA | I _B = 0 mA | 35.0 | --- | --- | V |
| BV _{ebo} | I _E = 10 mA | I _C = 0 mA | 4.0 | --- | --- | V |
| I _{cbo} | V _{CB} = 30 V | I _E = 0 mA | --- | --- | 2.0 | mA |
| H _{FE} | V _{CE} = 5.0V | I _C = 500 mA | 10 | --- | 150 | --- |

DYNAMIC

| Symbol | Test Conditions | | | Value | | | Unit |
|------------------|-----------------------|-----------------------|-----------------------|-------|------|------|------|
| | | | | Min. | Typ. | Max. | |
| P _{OUT} | f = 150 MHz | P _{IN} = 12W | V _{CE} = 28V | 60.0 | --- | --- | W |
| P _G | f = 150 MHz | P _{IN} = 12W | V _{CE} = 28V | 7.0 | --- | --- | dB |
| C _{OB} | V _{CB} = 28V | f = 1 MHz | | --- | --- | 80.0 | pf |

IMPEDANCE DATA

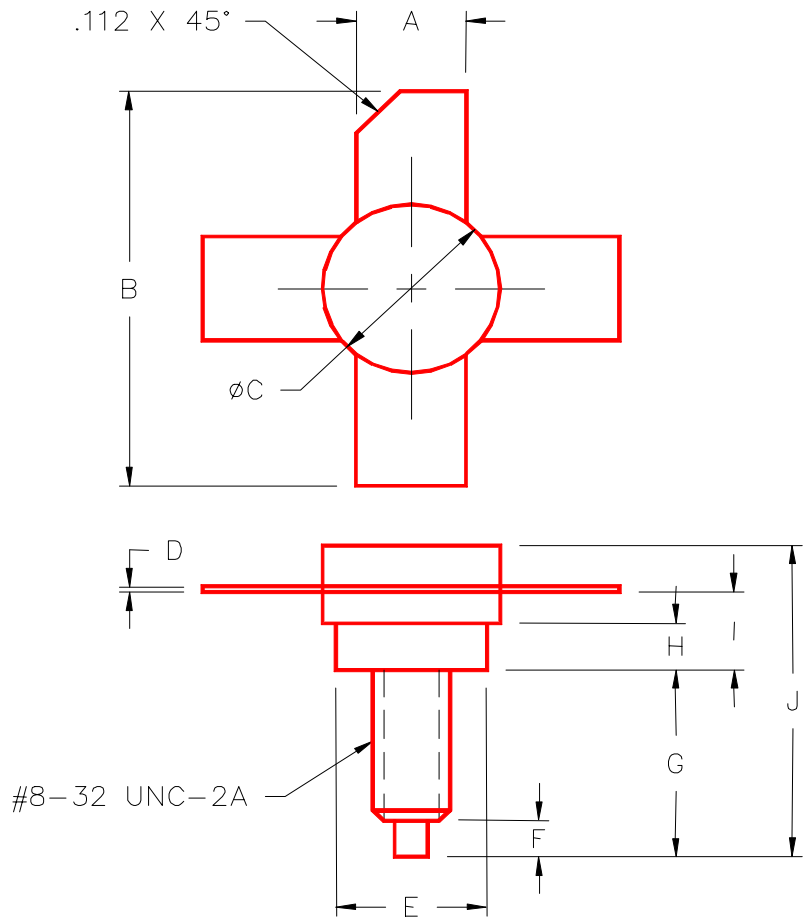
| FREQ | Z _{IN} (Ω) | Z _{CL} (Ω) |
|---------|---------------------|---------------------|
| 150 MHz | 1.0 + j2.0 | 4.0 - j3.9 |

P_{OUT} = 60W

V_{CE} = 28V

PACKAGE MECHANICAL DATA

PACKAGE STYLE M135



| | MINIMUM INCHES/MM | MAXIMUM INCHES/MM | | MINIMUM INCHES/MM | MAXIMUM INCHES/MM |
|---|----------------------|----------------------|---|----------------------|----------------------|
| A | .220/5,59 | .230/5,84 | I | .155/3,94 | .175/4,45 |
| B | .980/24,89 | | J | | .750/19,05 |
| C | .370/9,40 | .385/9,78 | | | |
| D | .004/0,10 | .007/0,18 | | | |
| E | .320/8,13 | .330/8,38 | | | |
| F | .100/2,54 | .130/3,30 | | | |
| G | .450/11,43 | .490/12,45 | | | |
| H | .090/2,29 | .100/2,54 | | | |